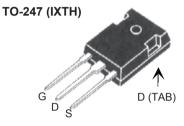


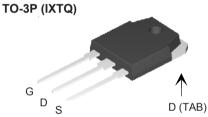
PolarHV[™] Power MOSFET

N-Channel Enhancement Mode Avalanche Rated IXTH 30N60P IXTQ 30N60P IXTT 30N60P IXTV 30N60PS $V_{DSS} = 600 V \ I_{D25} = 30 A \ R_{DS(on)} \le 240 m\Omega$

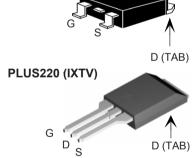


| Symbol | Test Conditions | Maximum Ratings | | | |
|---|--|------------------------------|-----------------------------|--------------------|--|
| V _{DSS} | $T_J = 25^{\circ} \text{ C to } 150^{\circ}$ | С | 600 | V | |
| $\mathbf{V}_{\mathtt{DGR}}$ | $T_{_{\rm J}}$ = 25° C to 150° | C; R_{GS} = 1 $M\Omega$ | 600 | V | |
| V _{GSS} | Continuous | | ±30 | V | |
| V _{GSM} | Transient | | ±40 | V | |
| I _{D25} | T _C = 25° C | | 30 | A | |
| I _{DM} | $T_{\rm C} = 25^{\circ} \text{C}$, pulse v | width limited by $T_{_{JM}}$ | 80 | Α | |
| I _{AR} | T _C = 25° C | | 30 | А | |
| E _{AR} | T _c = 25° C | | 50 | mJ | |
| E _{AS} | T _C = 25° C | | 1.5 | J | |
| dv/dt | $I_{S} \leq I_{DM}$, di/dt \leq 100 A/ μ s, $V_{DD} \leq V_{DSS}$, $T_{J} \leq$ 150° C, $R_{G} = 4 \Omega$ | | 10 | V/ns | |
| $\overline{P_{D}}$ | T _C = 25° C | | 540 | W | |
| T _J T _{JM} T _{stg} | | | -55 +150 150 -55 +150 | °C °C °C | |
| T _L T _{SOLD} | 1.6 mm (0.062 in.) Plastic body for 10 | from case for 10 s | 300 260 | °C °C | |
| M _d F _c | Mounting torque Mounting force | (TO-3P, TO-247) (PLUS220) | 1.13/10 1165/2.515 | Nm/lb.in. N/lb. | |
| Weight | TO-247 TO-3P PLUS220 TO-268 | | 6.0 5.5 4.0 5.0 | g g g | |

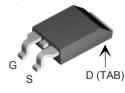




TO-268 (IXTT)



PLUS220 (IXTV...S)



| G = Gate |
|------------|
| S = Source |

D = Drain TAB = Drain

Features

- Fast Recovery diode
- Unclamped Inductive Switching (UIS) rated
- ¹ International standard packages
- Low package inductance
 - easy to drive and to protect

| | | | aracteristic Values Typ. | | | |
|---------------------|--|-------------------------|-------------------------------|--|-----------|--------------------------|
| BV _{DSS} | $V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$ | | 600 | | | V |
| V _{GS(th)} | $V_{DS} = V_{GS}$, $I_{D} = 250 \mu A$ | | 3.0 | | 5.0 | V |
| I _{GSS} | $V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$ | | | | ±100 | nA |
| I _{DSS} | $V_{DS} = V_{DSS}$ $V_{GS} = 0 V$ | T _J = 125° C | | | 25 250 | μ Α μ Α |
| R _{DS(on)} | $V_{GS} = 10 \text{ V}, I_{D} = 0.5 I_{D25}$ Pulse test, t \le 300 \mus, duty | cycle d ≤ 2 % | | | 240 | mΩ |

| Symbol | Test Conditions (T. = 25° C. u | Characteristic Values = 25° C, unless otherwise specified) | | |
|------------------------------|--|--|------|------------|
| | , J | Min. | | |
| g _{fs} | $V_{DS} = 20 \text{ V}; I_{D} = 0.5 I_{D25}, \text{ pulse test}$ | 22 | 25 | S |
| C _{iss} | | | 5050 | pF |
| C _{oss} | $V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$ | | 540 | pF |
| C _{rss} | | | 53 | pF |
| t _{d(on)} | | | 29 | ns |
| t _r | $V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ I}_{D25}$ | | 20 | ns |
| $\mathbf{t}_{d(off)}$ | $R_G = 4 \Omega $ (External) | | 80 | ns |
| $\mathbf{t}_{_{\mathrm{f}}}$ | | | 25 | ns |
| $\mathbf{Q}_{g(on)}$ | | | 82 | nC |
| \mathbf{Q}_{gs} | $V_{GS} = 10 \text{ V}, V_{DS} = 0.5 V_{DSS}, I_{D} = 0.5 I_{D25}$ | | 28 | nC |
| \mathbf{Q}_{gd} | | | 30 | nC |
| R _{thJC} | | | | 0.23 ° C/W |
| R _{thCS} | | | 0.21 | ° C/W |

Source-Drain Diode

Characteristic Values

(T_J = 25° C, unless otherwise specified)

| Symbol | Test Conditions | Min. | Тур. | Max. | |
|----------------------------|---|------|------|------|----|
| I _s | V _{GS} = 0 V | | | 30 | Α |
| I _{SM} | Repetitive | | | 80 | A |
| $\mathbf{V}_{\mathtt{SD}}$ | $I_F = I_S$, $V_{GS} = 0 \text{ V}$, Pulse test, t ≤300 μ s, duty cycle d≤ 2 % | | | 1.5 | V |
| t _{rr} | I _F = 25A, -di/dt = 100 A/μs | | 500 | | ns |
| \mathbf{Q}_{RM} | V _R = 100V | | 4.0 | | μС |

Fig. 1. Output Characteristics

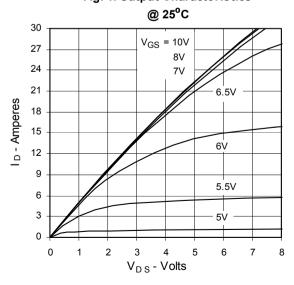
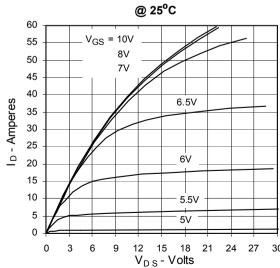


Fig. 2. Extended Output Characteristics



IXYS reserves the right to change limits, test conditions, and dimensions.

Fig. 3. Output Characteristics @ 125°C

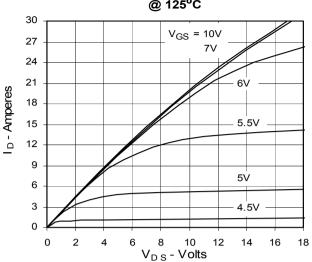


Fig. 4. R_{DS(on)} Normalized to 0.5 I_{D25} Value vs. Junction Temperature

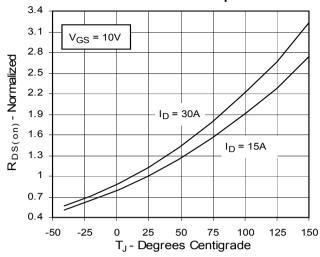


Fig. 5. $R_{DS(on)}$ Normalized to 0.5 I_{D25} Value vs. I_D

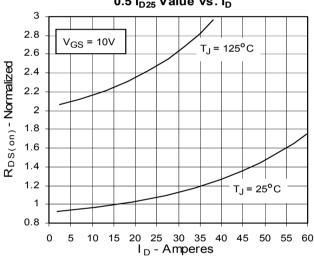


Fig. 6. Drain Current vs. Case

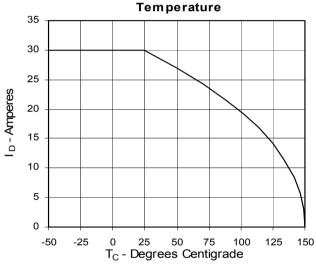


Fig. 7. Input Admittance

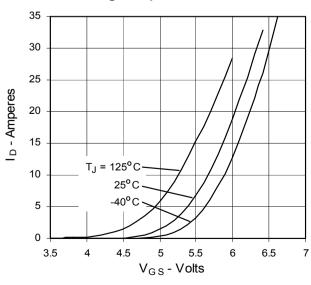


Fig. 8. Transconductance

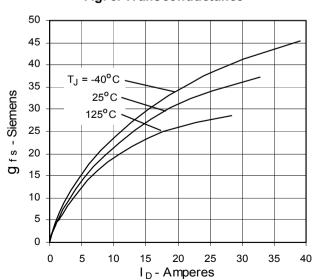




Fig. 9. Source Current vs. Source-To-Drain Voltage

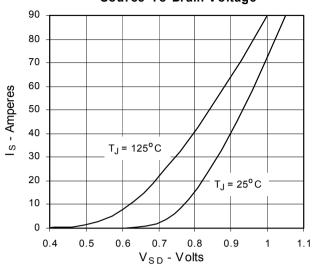


Fig. 10. Gate Charge

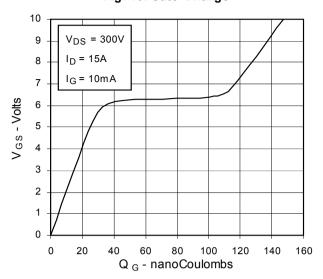


Fig. 11. Capacitance

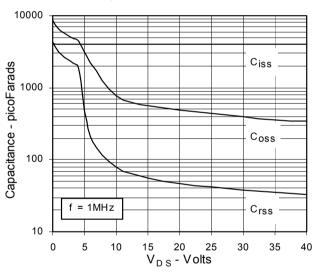


Fig. 12. Forward-Bias Safe Operating Area

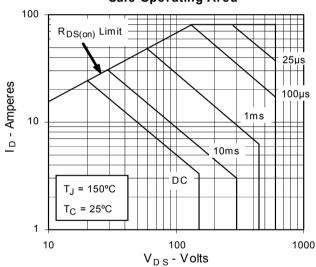
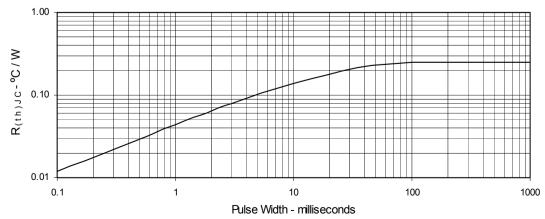


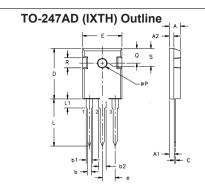
Fig. 13. Maximum Transient Thermal Resistance



IXYS reserves the right to change limits, test conditions, and dimensions.



Package Outline Drawings

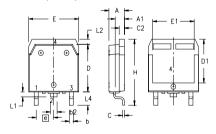


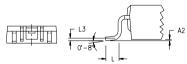
Terminals: 1 - Gate 3 - Source

2 - Drain Tab - Drain

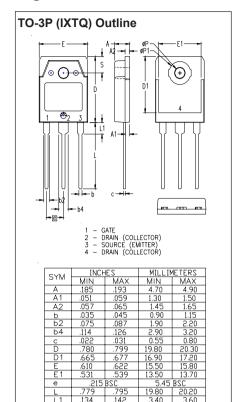
| Dim. | Millimeter | | Inches | |
|----------------|------------|-------|---------|-------|
| | Min. | Max. | Min. Ma | |
| Α | 4.7 | 5.3 | .185 | .209 |
| A ₁ | 2.2 | 2.54 | .087 | .102 |
| A ₂ | 2.2 | 2.6 | .059 | .098 |
| b | 1.0 | 1.4 | .040 | .055 |
| b₁ | 1.65 | 2.13 | .065 | .084 |
| b ₂ | 2.87 | 3.12 | .113 | .123 |
| С | .4 | .8 | .016 | .031 |
| D | 20.80 | 21.46 | .819 | .845 |
| Е | 15.75 | 16.26 | .610 | .640 |
| е | 5.20 | 5.72 | 0.205 | 0.225 |
| L | 19.81 | 20.32 | .780 | .800 |
| L1 | | 4.50 | | .177 |
| ØP | 3.55 | 3.65 | .140 | .144 |
| Q | 5.89 | 6.40 | 0.232 | 0.252 |
| R | 4.32 | 5.49 | .170 | .216 |
| S | 6.15 | BSC | 242 | BSC |

TO-268 (IXTT) Outline

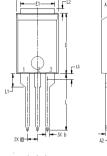


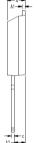


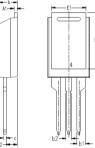
| MYZ | INCHES | | MILLIMETERS | |
|---------|----------|------|-------------|-------|
| 2114 | MIN | MAX | MIN | MAX |
| Α | .193 | .201 | 4.90 | 5.10 |
| A1 | .106 | .114 | 2.70 | 2.90 |
| A2 | .001 | .010 | 0.02 | 0.25 |
| b | .045 | .057 | 1.15 | 1.45 |
| b2 | .075 | .083 | 1.90 | 2.10 |
| C C2 | .016 | .026 | 0.40 | 0.65 |
| C2 | .057 | .063 | 1.45 | 1.60 |
| D | .543 | .551 | 13.80 | 14.00 |
| D1 | .488 | .500 | 12.40 | 12.70 |
| Е | .624 | .632 | 15.85 | 16.05 |
| E1 | .524 | .535 | 13.30 | 13.60 |
| е | .215 | BSC | 5.45 BSC | |
| Н | .736 | .752 | 18.70 | 19.10 |
| L | .094 | .106 | 2.40 | 2.70 |
| L1 | .047 | .055 | 1.20 | 1.40 |
| L2 | .039 | .045 | 1.00 | 1.15 |
| L3 | .010 BSC | | 0.25 | BSC |
| L4 | .150 | .161 | 3.80 | 4.10 |











GATE DRAIN (COLLECTOR) SOURCE (EMITTER) DRAIN (COLLECTOR)

| CVM | INCHES | | MILLIMETER | | |
|-----|---------|------|------------|-------|--|
| MYZ | MIN | MAX | MIN | MAX | |
| Α | .169 | .185 | 4.30 | 4.70 | |
| Α1 | .028 | .035 | 0.70 | 0.90 | |
| A2 | .098 | .118 | 2.50 | 3.00 | |
| Д | .035 | .047 | 0.90 | 1.20 | |
| Б | .080 | .095 | 2.03 | 2.41 | |
| b2 | .054 | .064 | 1.37 | 1.63 | |
| n | .028 | .035 | 0.70 | 0.90 | |
| U | .551 | .591 | 14.00 | 15.00 | |
| D1 | .512 | .539 | 13.00 | 13.70 | |
| Е | .394 | .433 | 10.00 | 11.00 | |
| E1 | .331 | .346 | 8.40 | 8.80 | |
| е | .100BSC | | 2.54 BSC | | |
| _i | .512 | .551 | 13.00 | 14.00 | |
| L1 | .118 | .138 | 3,00 | 3,50 | |
| L2 | .035 | .051 | 0.90 | 1.30 | |
| L3 | .047 | .059 | 1.20 | 1.50 | |



Package Outline Drawings

